

## Turbo 2 ultrafast high voltage rectifier

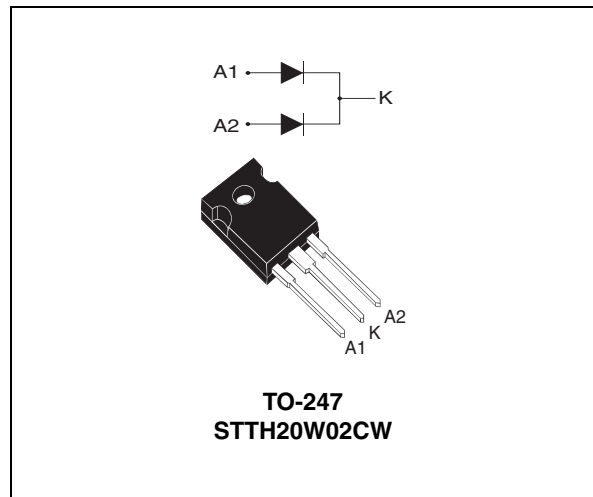
Datasheet – production data

### Features

- Ultrafast switching
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses
- ECOPACK<sup>®</sup>2 compliant component

### Description

The STTH20W02C uses ST Turbo 2 200 V technology. It is especially suited to be used for DC/DC and DC/AC converters in secondary stage of MIG/MMA/TIG welding machine. Housed in ST's TO-247, this device offers high power integration for all welding machines and industrial applications.



**Table 1. Device summary**

| Symbol         | Value    |
|----------------|----------|
| $I_{F(AV)}$    | 2 x 10 A |
| $V_{RRM}$      | 200 V    |
| $t_{rr}$ (typ) | 20 ns    |
| $T_j$          | 175 °C   |
| $V_F$ (typ)    | 0.89 V   |

# 1 Characteristics

**Table 2. Absolute ratings (limiting values, at 25 °C, unless otherwise specified)**

| Symbol       | Parameter                               |                                 | Value        | Unit |   |
|--------------|---|---------------------------------|--------------|------|---|
| $V_{RRM}$    | Repetitive peak reverse voltage         |                                 | 200          | V    |   |
| $I_{F(RMS)}$ | RMS forward current                     |                                 | 20           | A    |   |
| $I_{F(AV)}$  | Average forward current, $\delta = 0.5$ | $T_c = 120\text{ °C}$           | Per diode    | 10   | A |
|              |   | $T_c = 110\text{ °C}$           | Per device   | 20   |   |
| $I_{FSM}$    | Surge non repetitive forward current    | $t_p = 10\text{ ms}$ sinusoidal |              | 80   | A |
| $T_{stg}$    | Storage temperature range               |                                 | -65 to + 175 | °C   |   |
| $T_j$        | Maximum operating junction temperature  |                                 | + 175        | °C   |   |

**Table 3. Thermal resistance**

| Symbol        | Parameter        |           | Value | Unit   |
|---------------|------------------|-----------|-------|--------|
| $R_{th(j-c)}$ | Junction to case | Per diode | 4     | °C / W |
|               |                  | Total     | 2.5   | °C / W |
| $R_{th(c)}$   | Coupling         |           | 1     | °C / W |

When diodes 1 and 2 are used simultaneously:

$$T_{j(\text{diode } 1)} = P_{(\text{diode } 1)} \times R_{th(j-c)}(\text{Per diode}) + P_{(\text{diode } 2)} \times R_{th(c)}$$

**Table 4. Static electrical characteristics**

| Symbol      | Parameter               | Test conditions       |                     | Min. | Typ  | Max. | Unit          |
|-------------|-------------------------|-----------------------|---------------------|------|------|------|---------------|
| $I_R^{(1)}$ | Reverse leakage current | $T_j = 25\text{ °C}$  | $V_R = V_{RRM}$     |      |      | 5    | $\mu\text{A}$ |
|             |                         | $T_j = 125\text{ °C}$ |                     |      | 3    | 30   |               |
| $V_F^{(2)}$ | Forward voltage drop    | $T_j = 25\text{ °C}$  | $I_F = 10\text{ A}$ |      |      | 1.20 | V             |
|             |                         | $T_j = 150\text{ °C}$ |                     |      | 0.89 | 1.05 |               |
|             |                         | $T_j = 25\text{ °C}$  | $I_F = 20\text{ A}$ |      |      | 1.40 |               |
|             |                         | $T_j = 150\text{ °C}$ |                     |      | 1.10 | 1.30 |               |

1. Pulse test:  $t_p = 5\text{ ms}$ ,  $\delta < 2\%$

2. Pulse test:  $t_p = 380\text{ }\mu\text{s}$ ,  $\delta < 2\%$

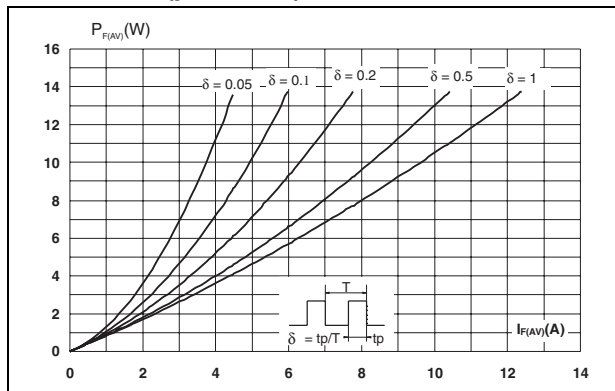
To evaluate the conduction losses use the following equation:

$$P = 0.8 \times I_{F(AV)} + 0.025 I_{F(RMS)}^2$$

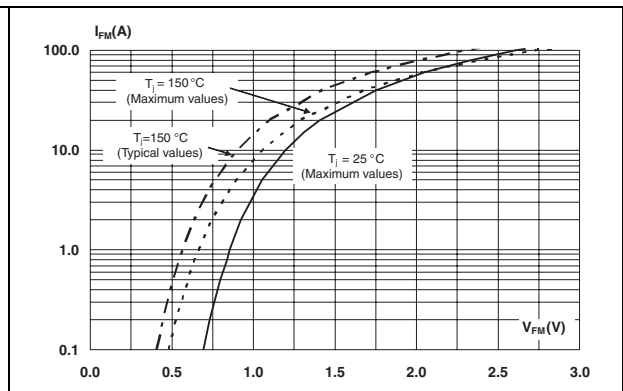
**Table 5. Dynamic electrical characteristics**

| Symbol       | Parameter                | Test conditions                   |  | Min. | Typ | Max. | Unit |
|--------------|--------------------------|-----------------------------------|--|------|-----|------|------|
| $I_{RM}$     | Reverse recovery current | $T_j = 125\text{ }^\circ\text{C}$ | $I_F = 10\text{ A}, V_R = 160\text{ V}$<br>$di_F/dt = -200\text{ A}/\mu\text{s}$ |      | 7   | 9    | A    |
| $Q_{RR}$     | Reverse recovery charge  |                                   |  |      | 150 |      | nC   |
| $S_{factor}$ | Softness factor          |                                   |  |      | 0.4 |      |      |
| $t_{rr}$     | Reverse recovery time    | $T_j = 25\text{ }^\circ\text{C}$  | $I_F = 1\text{ A}, V_R = 30\text{ V}$<br>$di_F/dt = -100\text{ A}/\mu\text{s}$   |      | 20  | 25   | ns   |
| $t_{fr}$     | Forward recovery time    | $T_j = 25\text{ }^\circ\text{C}$  | $I_F = 10\text{ A}, V_{FR} = 1\text{ V}$<br>$di_F/dt = 100\text{ A}/\mu\text{s}$ |      |     | 110  | ns   |
| $V_{FP}$     | Forward recovery voltage |                                   |  |      | 1.6 | 2.4  | V    |

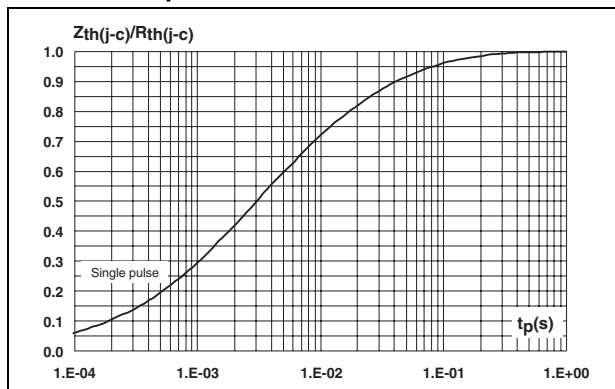
**Figure 1. Average forward power dissipation versus average forward current (per diode)**



**Figure 2. Forward voltage drop versus forward current (per diode)**



**Figure 3. Relative variation of thermal impedance junction to case versus pulse duration**



**Figure 4. Peak reverse recovery current versus di/dt (typical values, per diode)**

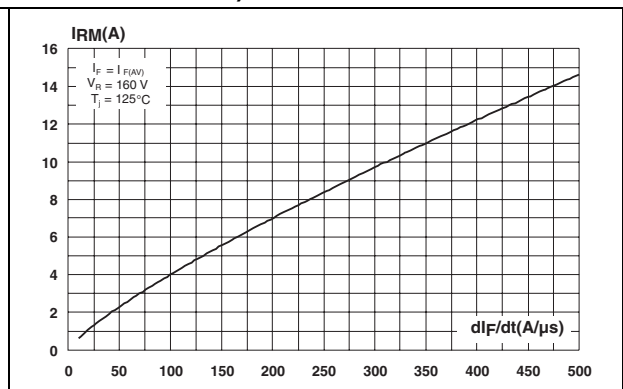


Figure 5. Reverse recovery time versus  $di_F/dt$  (typical values, per diode)

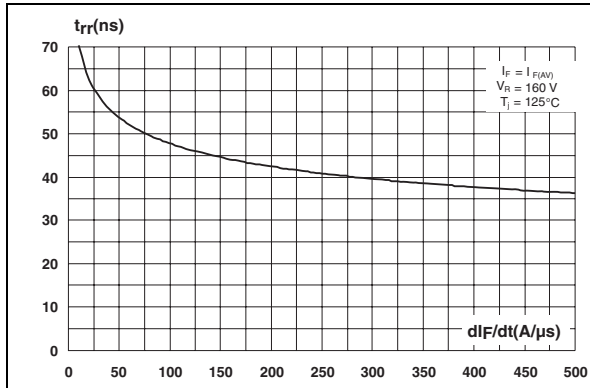


Figure 6. Reverse recovery charges versus  $di_F/dt$  (typical values, per diode)

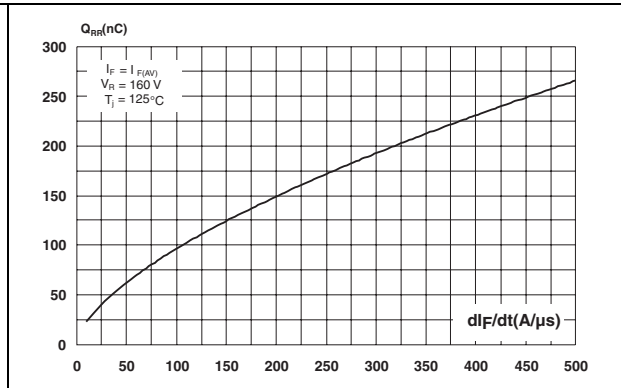


Figure 7. Relative variations of dynamic parameters versus junction temperature

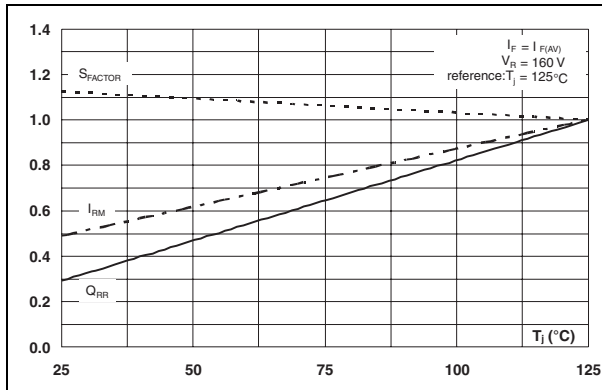


Figure 8. Reverse recovery softness factor versus  $di_F/dt$  (typical values, per diode)

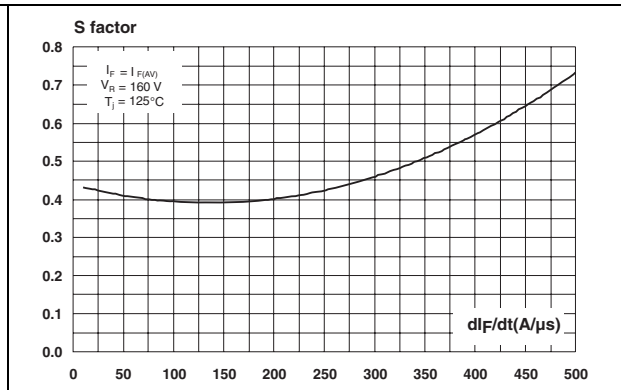


Figure 9. Forward recovery time versus  $di_F/dt$  (typical values, per diode)

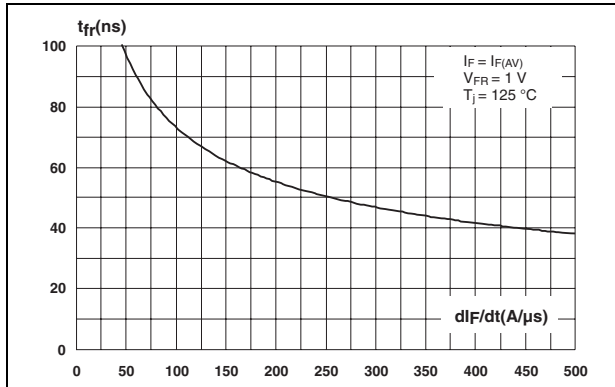


Figure 10. Transient peak forward voltage versus  $di_F/dt$  (typical values, per diode)

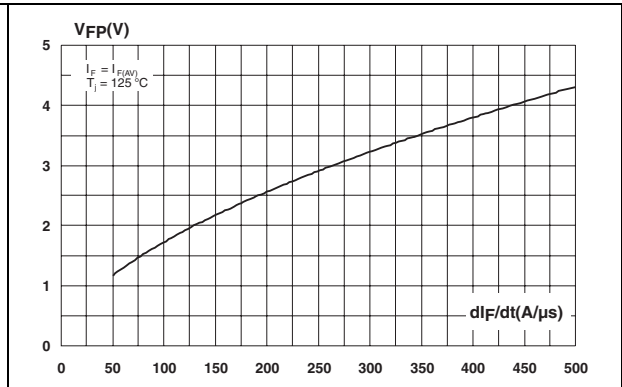
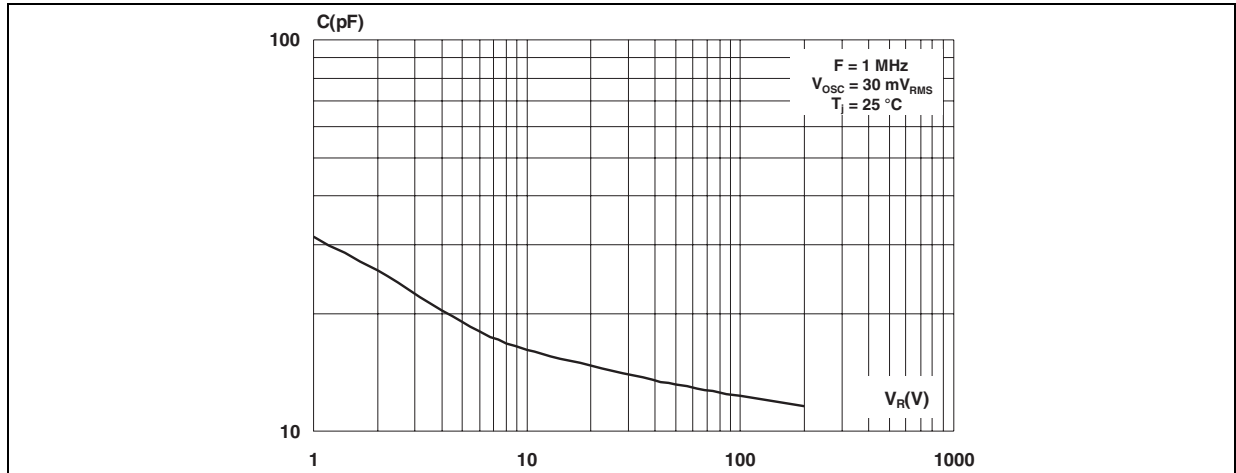


Figure 11. Junction capacitance versus reverse voltage applied (typical values, per diode)



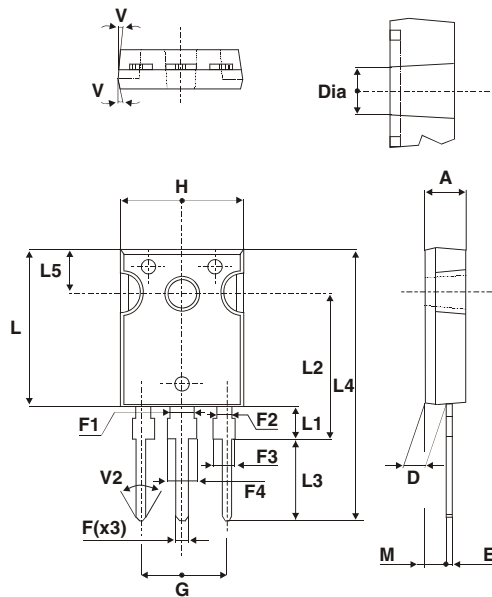
## 2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 N·m (1.0 N·m maximum)

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**Table 6. TO-247 dimensions**

| Ref. | Dimensions  |       |            |       |
|------|-------------|-------|------------|-------|
|      | Millimeters |       | Inches     |       |
|      | Min.        | Max.  | Min.       | Max.  |
| A    | 4.85        | 5.15  | 0.191      | 0.203 |
| D    | 2.20        | 2.60  | 0.086      | 0.102 |
| E    | 0.40        | 0.80  | 0.015      | 0.031 |
| F    | 1.00        | 1.40  | 0.039      | 0.055 |
| F1   | 3.00 typ.   |       | 0.118 typ. |       |
| F2   | 2.00 typ.   |       | 0.078 typ. |       |
| F3   | 2.00        | 2.40  | 0.078      | 0.094 |
| F4   | 3.00        | 3.40  | 0.118      | 0.133 |
| G    | 10.90 typ.  |       | 0.429 typ. |       |
| H    | 15.45       | 15.75 | 0.608      | 0.620 |
| L    | 19.85       | 20.15 | 0.781      | 0.793 |
| L1   | 3.70        | 4.30  | 0.145      | 0.169 |
| L2   | 18.50 typ.  |       | 0.728 typ. |       |
| L3   | 14.20       | 14.80 | 0.559      | 0.582 |
| L4   | 34.60 typ.  |       | 1.362 typ. |       |
| L5   | 5.50 typ.   |       | 0.216 typ. |       |
| M    | 2.00        | 3.00  | 0.078      | 0.118 |
| V    | 5° typ.     |       | 5° typ.    |       |
| V2   | 60° typ.    |       | 60° typ.   |       |
| Dia. | 3.55        | 3.65  | 0.139      | 0.143 |



### 3 Ordering information

Table 7. Ordering information

| Ordering type | Marking     | Package | Weight | Base qty | Delivery mode |
|---------------|-------------|---------|--------|----------|---------------|
| STTH20W02CW   | STTH20W02CW | TO-247  | 4.46 g | 50       | Tube          |

### 4 Revision history

Table 8. Document revision history

| Date        | Revision | Changes      |
|-------------|----------|--------------|
| 18-May-2012 | 1        | First issue. |

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